Technical Data Sheet



DP3T Ramses SMA 18GHz Latching Self-cut-off 12Vdc Positive common Diodes Pins terminals

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RF CHARACTERISTICS

Frequency range : 0 - 18 GHz Impedance : 50 Ohms

Frequency (GHz)	DC - 3	3 - 8	8 - 12.4	12.4 - 18
VSWR max	1.20	1.30	1.40	1.50
Insertion loss max	0.20 dB	0.30 dB	0.40 dB	0.50 dB
Isolation min	80 dB	70 dB	60 dB	60 dB
Average power (*)	240 W	150 W	120 W	100 W

ELECTRICAL CHARACTERISTICS

Actuator : LATCHING
Nominal current ** : 420 mA

Actuator voltage (Vcc) : 12V (10.2 to 13V) / POSITIVE COMMON Terminals : solder pins (250°C max. / 30 sec.)

Self cut-off time : 40 ms < CT < 120 ms

MECHANICAL CHARACTERISTICS

Connectors : SMA female per MIL-C 39012

Life : 10 million cycles

Switching Time*** : < 10 msConstruction : Splashproof
Weight : < 100 g

ENVIRONMENTAL CHARACTERISTICS

Operating temperature range : -40°C to +85°C Storage temperature range : -55°C to +85°C

(* Average power at 25°C per RF Path)

(** At 25° C ±10%)

(*** Nominal voltage; 25° C)



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